## 查询TPIC2322LD供应商 捷多邦,专业PCB打样工厂,24小时加急出货TPIC2322L 3-CHANNEL COMMON-SOURCE LOGIC-LEVEL POWER DMOS ARRAY

SLIS036A - JUNE 1994 - REVISED OCTOBER 1994

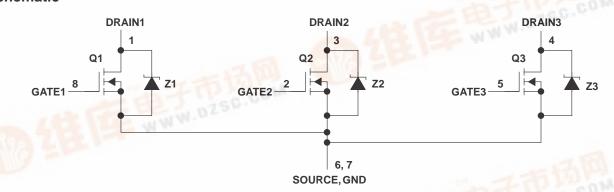
<ul> <li>Low r<sub>DS(on)</sub> 0.6 Ω Typ</li> <li>High-Voltage Outputs 60 V</li> </ul>	D PACKAGE (TOP VIEW)					
Pulsed Current 2.25 A Per Channel						
<ul> <li>Fast Commutation Speed</li> </ul>	GATE2 2 7 SOURCE/GND					
Direct Logic-Level Interface	DRAIN2 3 6 SOURCE/GND					
	DRAIN3 [ 4 5 ] GATE3					

#### description

The TPIC2322L is a monolithic logic-level power DMOS array that consists of three electrically isolated N-channel enhancement-mode DMOS transistors configured with a common source and open drains.

The TPIC2322L is offered in a standard eight-pin small-outline surface-mount (D) package and is characterized for operation over the case temperature range of  $-40^{\circ}$ C to  $125^{\circ}$ C.

#### schematic



#### absolute maximum ratings over operating case temperature range (unless otherwise noted)<sup>†</sup>

Drain-to-source voltage, V <sub>DS</sub>	
Drain-to-GND voltage	
Gate-to-source voltage, V <sub>GS</sub>	
Continuous drain current, each output, all outputs on, T <sub>C</sub> = 25°C	0.75 A
Continuous source-to-drain diode current, T <sub>C</sub> = 25°C	0.75 A
Pulsed drain current, each output, I <sub>max</sub> , T <sub>C</sub> = 25°C (see Note 1 and Figure 15)	2.25 A
Single-pulse avalanche energy, E <sub>AS</sub> , T <sub>C</sub> = 25°C (see Figure 4)	30.4 mJ
Continuous total power dissipation at (or below) $T_C = 25^{\circ}C$ (see Figure 15)	0.95 W
Operating virtual junction temperature range, T	–40°C to 150°C
Operating case temperature range, T <sub>C</sub>	–40°C to 125°C
Storage temperature range	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
 NOTE 1: Pulse duration = 10 ms and duty cycle = 2%.



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### electrical characteristics, $T_C = 25^{\circ}C$ (unless otherwise noted)

	PARAMETER	TEST COND	MIN	TYP	MAX	UNIT	
V(BR)DSX	Drain-to-source breakdown voltage	I <sub>D</sub> = 250 μA,	$V_{GS} = 0$	60			V
VGS(th)	Gate-to-source threshold voltage	I <sub>D</sub> = 1 mA, See Figure 5	$V_{DS} = V_{GS}$ ,	1.5	1.85	2.2	V
V <sub>(BR)</sub>	Reverse drain to GND breakdown voltage	Drain to GND current	: = 250 μA	100			V
V <sub>DS(on)</sub>	Drain-to-source on-state voltage	$I_D = 0.75 A$ , See Notes 2 and 3	V <sub>GS</sub> = 5 V,		0.45	0.53	V
V <sub>F(SD)</sub>	Forward on-state voltage, source-to-drain	I <sub>S</sub> = 0.75 A, See Notes 2 and 3 ar	V <sub>GS</sub> = 0 nd Figure 12		0.85	1	V
		V <sub>DS</sub> = 48 V,	$T_C = 25^{\circ}C$		0.05	1	
DSS	Zero-gate-voltage drain current	$V_{GS} = 0$	$T_{C} = 125^{\circ}C$		0.5	).5 10	μA
IGSSF	Forward gate current, drain short circuited to source	V <sub>GS</sub> = 16 V,	$V_{DS} = 0$		10	100	nA
IGSSR	Reverse gate current, drain short circuited to source	V <sub>SG</sub> = 16 V,	$V_{DS} = 0$		10	100	nA
	Leakage current, drain-to-GND	V <sub>DGND</sub> = 48 V	$T_C = 25^{\circ}C$		0.05	1	
l <sub>lkg</sub>			$T_{C} = 125^{\circ}C$		0.5	10	μA
	Static drain-to-source on-state resistance	V <sub>GS</sub> = 5 V, I <sub>D</sub> = 0.75 A,	T <sub>C</sub> = 25°C		0.6	0.7	Ω
rDS(on)		See Notes 2 and 3 and Figures 6 and 7	T <sub>C</sub> = 125°C		0.94	1	52
9fs	Forward transconductance	$V_{DS} = 15 V$ , See Notes 2 and 3 ar	I <sub>D</sub> = 0.5 A, nd Figure 9	0.75	0.9		S
C <sub>iss</sub>	Short-circuit input capacitance, common source				115	145	
C <sub>OSS</sub>	Short-circuit output capacitance, common source	$V_{DS} = 25 V, V_{GS} = 0,$	00		60	75	pF
C <sub>rss</sub>	Short-circuit reverse transfer capacitance, common source	f = 1 MHz,	= 1 MHz, See Figure 11		30	40	ΡĽ

NOTES: 2. Technique should limit T<sub>J</sub> – T<sub>C</sub> to 10°C maximum.
 3. These parameters are measured with voltage-sensing contacts separate from the current-carrying contacts.

### source-to-drain diode characteristics, $T_C = 25^{\circ}C$ (see schematic diagram)

	PARAMETER	TEST C	MIN	TYP	MAX	UNIT	
t <sub>rr</sub>	Reverse-recovery time	I <sub>F</sub> = 0.375 A,	V <sub>DS</sub> = 48 V,		85		ns
Q <sub>RR</sub>	Total diode charge	di/dt = 100 A/µs,	See Figures 1 and 14		0.19		μC



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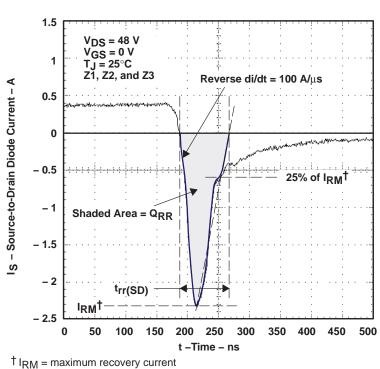
### resistive-load switching characteristics, $T_C = 25^{\circ}C$

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
<sup>t</sup> d(on)	Turn-on delay time					21	42	
<sup>t</sup> d(off)	Turn-off delay time	V <sub>DD</sub> = 25 V,	R <sub>L</sub> = 67 Ω,	t <sub>en</sub> = 10 ns,		26	52	
t <sub>r</sub>	Rise time	t <sub>dis</sub> = 10 ns,	See Figure 2			14	28	ns
t <sub>f</sub>	Fall time					13	26	
Qg	Total gate charge					1.8	2.3	
Q <sub>gs(th)</sub>	Threshold gate-to-source charge	$V_{DS} = 48 V,$ See Figure 3		VGS = 5 V,		0.4	0.5	nC
Q <sub>gd</sub>	Gate-to-drain charge					1.1	1.4	
LD	Internal drain inductance					5		
LS	Internal source inductance					5		nH
Rg	Internal gate resistance					0.25		Ω

#### thermal resistance

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance, See Note 4	All outputs with equal power		130		°C/W
$R_{\theta JP}$	Junction-to-pin thermal resistance			44		°C/W

NOTE 4: Package mounted on an FR4 printed-circuit board with no heat sink.

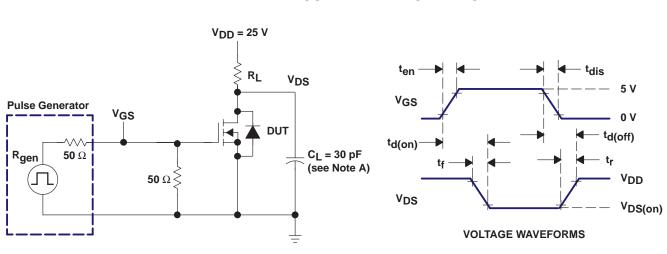


#### PARAMETER MEASUREMENT INFORMATION

Figure 1. Reverse-Recovery-Current Waveform of Source-to-Drain Diode



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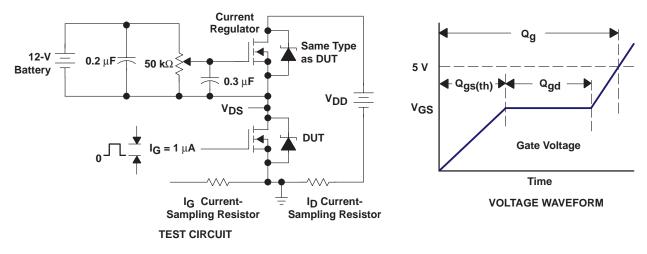


PARAMETER MEASUREMENT INFORMATION

**TEST CIRCUIT** 

NOTE A: CL includes probe and jig capacitance.

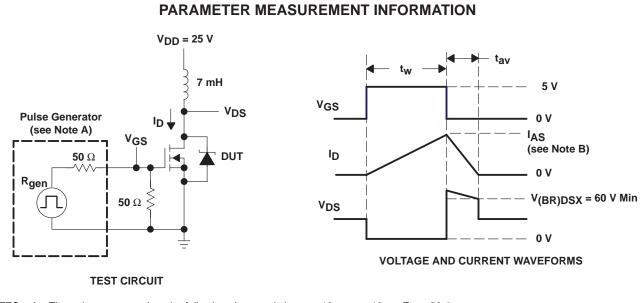








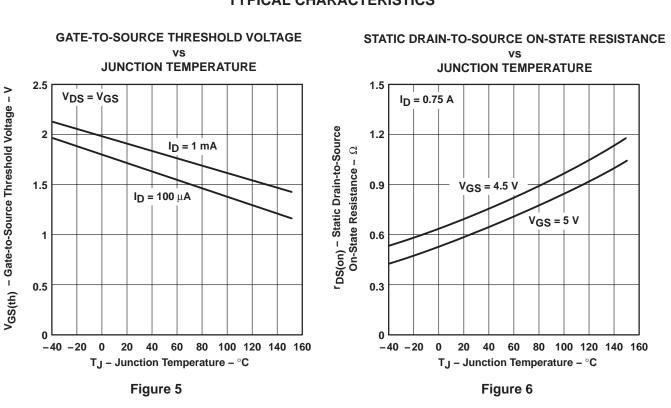
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NOTES: A. The pulse generator has the following characteristics:  $t_r \le 10$  ns,  $t_f \le 10$  ns,  $Z_O = 50 \Omega$ . B. Input pulse duration ( $t_W$ ) is increased until peak current I<sub>AS</sub> = 2.25 A.

Energy test level is defined as  $E_{AS} = \frac{I_{AS} \times V_{(BR)DSX} \times t_{av}}{2} = 30.4 \text{ mJ}.$ 

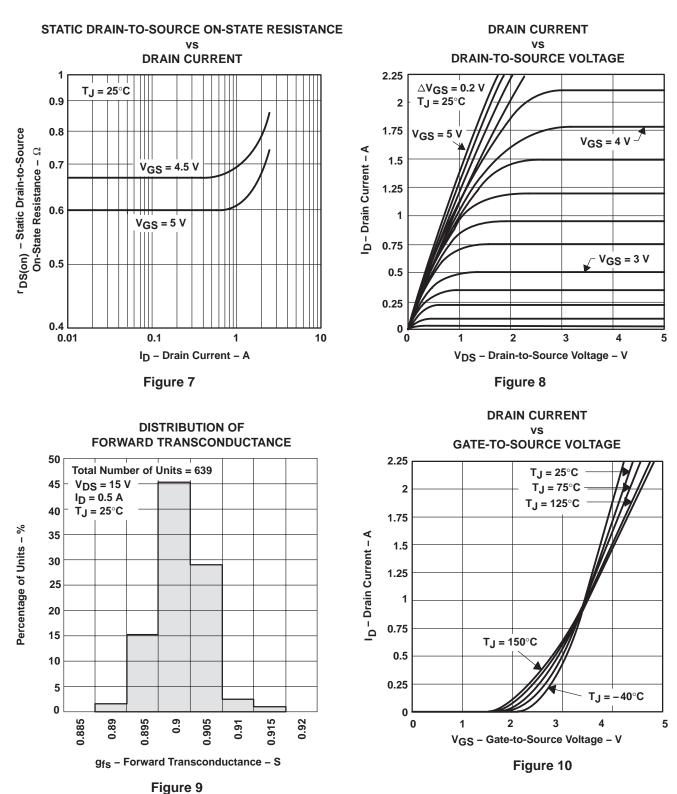
Figure 4. Single-Pulse Avalanche Energy Test Circuit and Waveforms







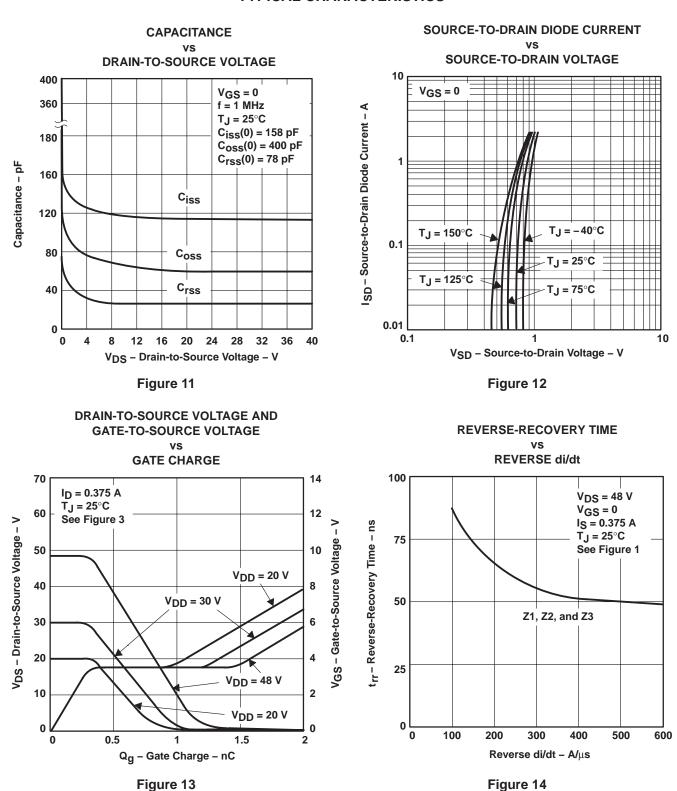
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**TYPICAL CHARACTERISTICS** 



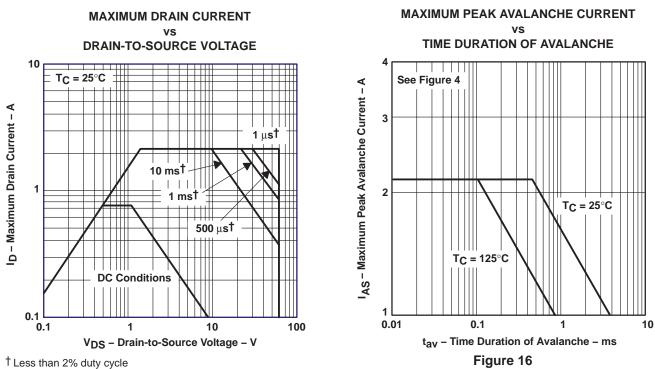
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**TYPICAL CHARACTERISTICS** 



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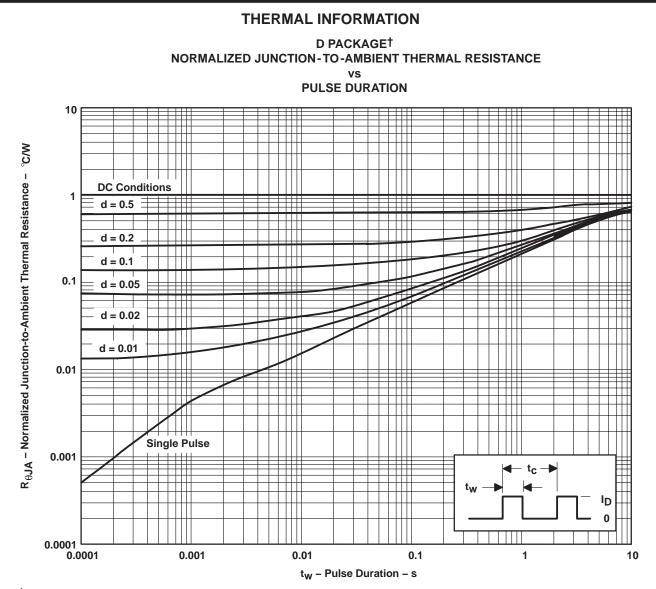


#### **THERMAL INFORMATION**

Figure 15



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<sup>†</sup> Device mounted on FR4 printed-circuit board with no heat sink.

NOTES:  $Z_{\theta A}(t) = r(t) R_{\theta JA}$  $t_W =$  pulse duration  $t_C =$  cycle time

 $d = duty cycle = t_W/t_C$ 

Figure 17



8-Apr-2005

#### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TPIC2322LD	OBSOLETE	SOIC	D	8	TBD	Call TI	Call TI

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

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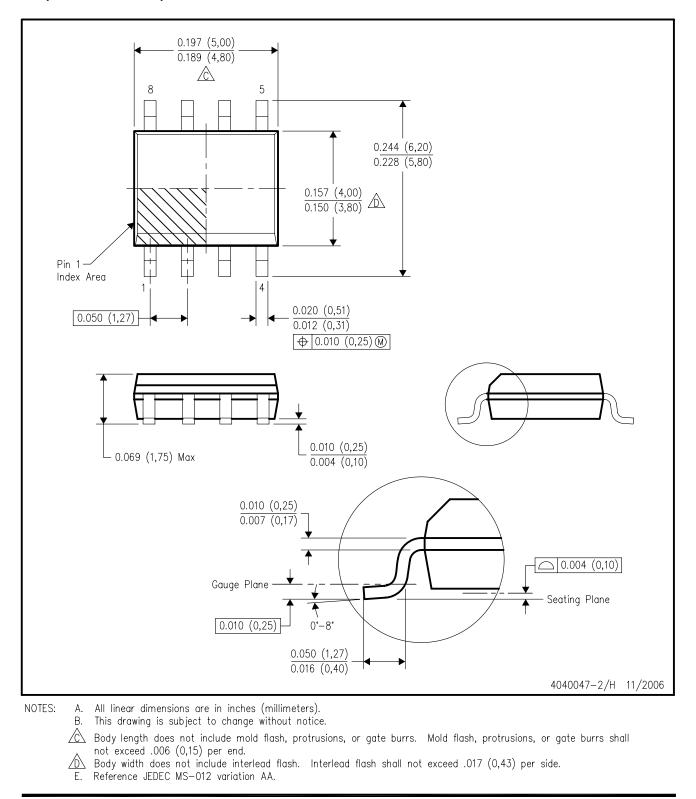
<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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